## **Electronic Supplementary Information**

# Superior Catalytic Activity of Nitrogen-Doped Graphene Cathode for High Energy Capacity Sodium-Air Batteries

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### **Experimental details:**

#### Synthesis of Graphene Nanosheets (GNSs)

Graphene nanosheets (GNSs) were prepared by the oxidation of graphite powder using the modified Hummers' method.<sup>1</sup> Typically, graphite powder (1 g), sodium nitrate (0.75 g) and potassium permanganate (4.5 g) were added to concentrated sulphuric acid (37.5 mL) and stirred for 2 h in an ice water bath. Then the mixture was stirred for five days at room temperature. 100 mL of 5 wt% H<sub>2</sub>SO<sub>4</sub> and 3 g of 30 wt% H<sub>2</sub>O<sub>2</sub> were added into the above mixture in sequence under stirring with interval of 1 h. After stirring for 2 h, the sample was filtered and washed until the pH=7. The as-received sample was dried and heated at 1050 °C for 30 s under Ar to produce GNSs.<sup>2</sup>

#### **Physical Characterizations**

The morphology of the discharge products of GNSs and N-GNSs electrodes were characterized by a Hitachi S-4800 field emission scanning electron microscopy (FESEM). Raman scattering (RS) spectra were recorded on a HORIBA Scientific LabRAM HR Raman spectrometer system equipped with a 532.4 nm laser. The XRD pattern was recorded by a Bruker-AXS D8 Discover diffractometer employing a Cu-K $\alpha$  source ( $\lambda$ =1.5374 Å).

#### **Electrochemical Measurements**

Swagelok type cells were used to test the battery performance. GNSs or N-GNSs and PVDF (Alfa Aesar) with a weight ratio of 9:1 were casted onto a separator (Celgard 3500) as cathode. The

electrodes were cut to 3/8 inch in diameter and the loadings of GNSs or N-GNSs were ~0.3 mg. The electrolyte was 0.5 mol dm<sup>-3</sup> NaSO<sub>3</sub>CF<sub>3</sub> dissolved in diethylene glycol dimethyl ether (C<sub>6</sub>H<sub>14</sub>O<sub>3</sub>, diglyme, DEGDME). The discharge/charge characteristics were performed using an Arbin BT-2000 battery station in a voltage range of 1.8-3.6 V in a 1 atm oxygen atmosphere at room temperature (25 °C). Cyclic voltammetry (CV) measurements were carried out using a CHI 600c electrochemical work station at a scan rate of 2 mV s<sup>-1</sup> in a voltage range of 1.8-3.6 V at room temperature. In order to study the cycleability of batteries utilizing GNSs and N-GNSs electrodes, the batteries were discharged at a current density of 75 mA g<sup>-1</sup>, delivering a discharge capacity of 1150 mAh g<sup>-1</sup>, and then proceeded the charge process until voltage reached to 3.6 V. Electrochemical impedance spectra were recorded in the frequency range of 0.01-10<sup>5</sup> Hz using a VMP3 Potentiostat (BioLogic Science Instruments). The resulted spectra were fitted by ZView software.

#### References

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Fig. S1 Raman spectra of GNSs and N-GNSs.



**Fig. S2** Measured and calculated electrochemical impedance spectra of GNSs and N-GNSs electrodes after discharge at 75 mA g<sup>-1</sup>. The inset is the equivalent circuit used for the analysis of the impedance plots.

	$R_e/\Omega$	$R_{int}/F$	$C_{int}/\Omega$	$R_{ct}/\Omega$	$C_m/F$	$W_o/\Omega$
N-GNSs	36.4	655.6	$2.46e^{-6}$	663.7	47.9e <sup>-6</sup>	0.274
GNSs	38.0	517.1	$5.76e^{-6}$	1556.0	94.4e <sup>-6</sup>	0.284

Table S1. Dependence of equivalent-circuit parameters for GNSs and N-GNSs electrodes.

 $R_e$  is the ionic resistance of electrolyte;  $R_{int}$  and  $C_{int}$  are the interfacial resistance and capacitance of film on the interface between electrode/electrolyte, respectively;  $R_{ct}$  is the charge-transfer resistance while  $C_m$  is the parallel capacitance for the semicircle accordingly, and  $W_o$  is the finite length Warburg resistance.<sup>1</sup>

#### References

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Fig. S3 SEM images of discharge products on N-GNSs electrodes at (a) 150, and (b) 300

 $mAg^{-1}$ .



Fig. S4 Schematic of the growth of discharge product nanostructures on N-GNS

electrodes.